

RD74LVC1G240

Bus Buffer Inverted with 3-state Output

REJ03D0733-0100 Rev.1.00 Apr 13, 2006

Description

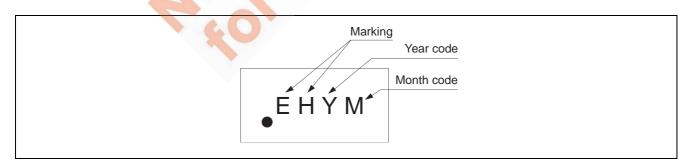
The RD74LVC1G240 has bus buffer inverted with 3–state output in a 5-pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as renesas uni logic series.
- Supply voltage range: 1.65 to 5.5 V
- Operating temperature range: -40 to +85°C
- All inputs: V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- All outputs: V_0 (Max.) = 5.5 V (@ V_{CC} = 0 V)
- Output current: $\pm 4 \text{ mA } (@V_{CC} = 1.65 \text{ V})$
 - $\pm 8 \text{ mA} (@V_{CC} = 2.3 \text{ V})$
 - $\pm 24 \text{ mA} (@V_{CC} = 3.0 \text{ V})$
 - $\pm 32 \text{ mA} (@V_{CC} = 4.5 \text{ V})$
- Ordering Information

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Part Name	Package Type	Package Code	Package	Taping Abbreviation
		(Previous Code)	Abbreviation	(Quantity)
RD74LVC1G240WPE	WCSP-5 pin	SXBG0005LB-A	WP	E (3,000 pcs/reel)
		(TBS-5CV)		

Article Indication



Function Table

Inp		
ŌĒ	Α	Output Y
L	L	Н
L	Н	L
Н	X	Z

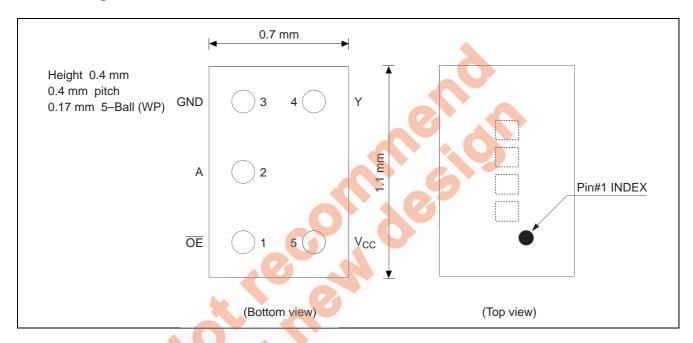
H: High level

L: Low level

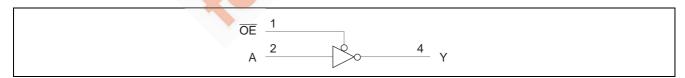
X: Immaterial

Z: High impedance

Pin Arrangement



Logic Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{CC}	-0.5 to 6.5	V	
Input voltage range *1	VI	-0.5 to 6.5	V	
Output voltage range *1, 2	Vo	-0.5 to V _{CC} +0.5	V	Output : H or L
		-0.5 to 6.5		V _{CC} : OFF or Output "Z"
Input clamp current	I _{IK}	-50	mA	V _I < 0
Output clamp current	I _{OK}	-50	mA	V _O < 0
Continuous output current	Io	±50	mA	$V_O = 0$ to V_{CC}
Continuous current through	I _{CC} or I _{GND}	±100	mA	
V _{CC} or GND				
Package Thermal impedance	θ_{ja}	200	°C/W	WP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	1.65	5.5	V	
Input voltage range	VI	0	5.5	V	
Output voltage range	Vo	0	Vcc	V	
		0	5.5		Output : Z
Output current	loL		4	mA	V _{CC} = 1.65 V
			8		$V_{CC} = 2.3 \text{ V}$
	*		16		$V_{CC} = 3.0 \text{ V}$
	1	_	24		
	1	_	32		$V_{CC} = 4.5 \text{ V}$
	Пон		-4		$V_{CC} = 1.65 \text{ V}$
	CO.		-8		$V_{CC} = 2.3 \text{ V}$
		_	-16		$V_{CC} = 3.0 \text{ V}$
		_	-24		
			-32		$V_{CC} = 4.5 \text{ V}$
Input transition rise or fall rate	Δt / Δv	0	20	ns / V	$V_{CC} = 1.65 \text{ to } 1.95 \text{ V},$
					2.3 to 2.7 V
		0	10		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		0	5		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

Ta = -40 to $85^{\circ}C$

Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	Test condition
Input voltage	V _{IH}	1.65 to 1.95	V _{CC} ×0.65	_	_	V	
		2.3 to 2.7	1.7	_	_		
		3.0 to 3.6	2.0	_	_		
		4.5 to 5.5	V _{CC} ×0.7	_	_		
	V_{IL}	1.65 to 1.95	_	_	V _{CC} ×0.35		
		2.3 to 2.7	_	_	0.7		
		3.0 to 3.6	_	_	0.8		
		4.5 to 5.5	_	_	V _{CC} ×0.3		
Output voltage	V_{OH}	Min to Max	V _{CC} -0.1	_	_	V	$I_{OH} = -100 \mu A$
		1.65	1.2	_	_		$I_{OH} = -4 \text{ mA}$
		2.3	1.9	_	_		$I_{OH} = -8 \text{ mA}$
		3.0	2.4	_	_		$I_{OH} = -16 \text{ mA}$
			2.3	_	_		$I_{OH} = -24 \text{ mA}$
		4.5	3.8	_			I _{OH} = -32 mA
	V_{OL}	Min to Max	_	_	0.1		l _{OL} = 100 μA
		1.65	_	_	0.45		I _{OL} = 4 mA
		2.3	_	-/-	0.3		I _{OL} = 8 mA
		3.0	_	-	0.4		I _{OL} = 16 mA
			_	4	0.55		I _{OL} = 24 mA
		4.5	- 7		0.55		$I_{OL} = 32 \text{ mA}$
Input current	I _{IN}	0 to 5.5	_ 6) — <u> </u>	±5	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Off state Output current	loz	3.6	(4)	_	10	μΑ	$V_O = 5.5 \text{ V or GND}$
Quiescent	I _{CC}	1.65 to 5.5	(d)		10	μA	$V_{IN} = V_{CC}$ or GND,
supply current			6			•	I _O = 0
	ΔI_{CC}	3 to 5.5	A	/_	500		One input at V _{CC} -0.6 V,
							Other input at V _{CC} or GND
Output leakage	I _{OFF}	0		_	±10	μΑ	V_{IN} or $V_O = 0$ to 5.5 V
current							
Input capacitance	C _{IN}	3.3	_	3.5	_	рF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

 $V_{CC}=1.8{\pm}0.15~V$

		Ta = -40 to 85°C				FROM	ТО
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	3.0	8.0	ns	$C_L = 30 \text{ pF}, R_L = 1.0 \text{ k}\Omega$	А	Υ
	t _{PHL}						
Output enable time	t _{ZH}	3.8	9.4	ns		OE	Υ
	t_{ZL}						
Output disable time	t _{HZ}	2.1	9.4	ns		ŌĒ	Υ
	t_{LZ}						

 $V_{CC} = 2.5 \pm 0.2 \text{ V}$

		Ta = -40 to 85°C				FROM	то
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	1.4	5.5	ns	$C_L = 30 \text{ pF}, R_L = 500 \Omega$	А	Υ
	t _{PHL}						
Output enable time	t _{ZH}	2.1	6.5	ns		OE	Υ
	t_{ZL}						
Output disable time	t _{HZ}	1.0	4.9	ns		OE	Υ
	t_{LZ}			6			

 $V_{CC} = 3.3 \pm 0.3 \text{ V}$

		Ta = -40) to 85°C			FROM	ТО
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	1.1	4.5	ns	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	А	Υ
	t _{PHL}						
Output enable time	t _{zH}	1.4	5.4	ns		OE	Υ
	t _{ZL}						
Output disable time	t _{HZ}	1.4	5.2	ns		ŌĒ	Υ
	t _{LZ}						

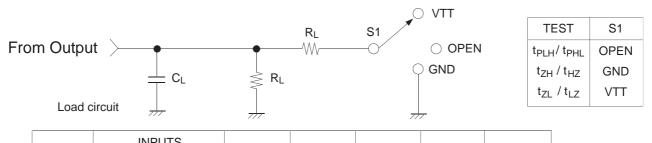
 $V_{CC} = 5.0 \pm 0.5 \text{ V}$

	4.0	Ta = -40	Ta = -40 to 85°C			FROM	ТО
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	1.0	4.0	ns	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	А	Υ
	t _{PHL}						
Output enable time	t _{ZH}	1.1	5.2	ns		ΘE	Υ
	t_{ZL}						
Output disable time	t _{HZ}	1.0	4.1	ns		OE	Υ
	t_{LZ}						

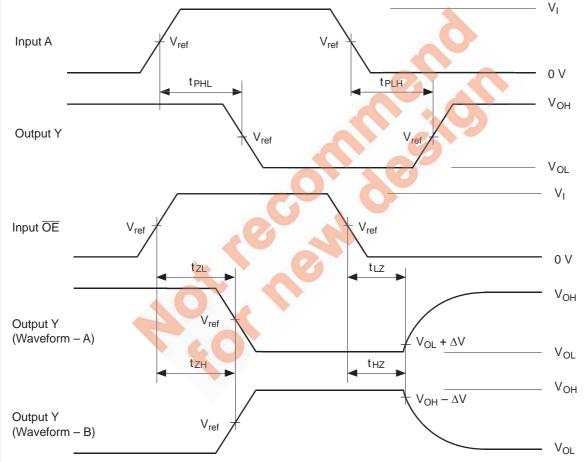
Operating Characteristics

				Ta = 25°C			
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation	C_{PD}	1.8	-	19	_	pF	f = 10 MHz
capacitance		2.5	_	19	_		
		3.3	_	20	_		
		5.0	_	22	_		

Test Circuit



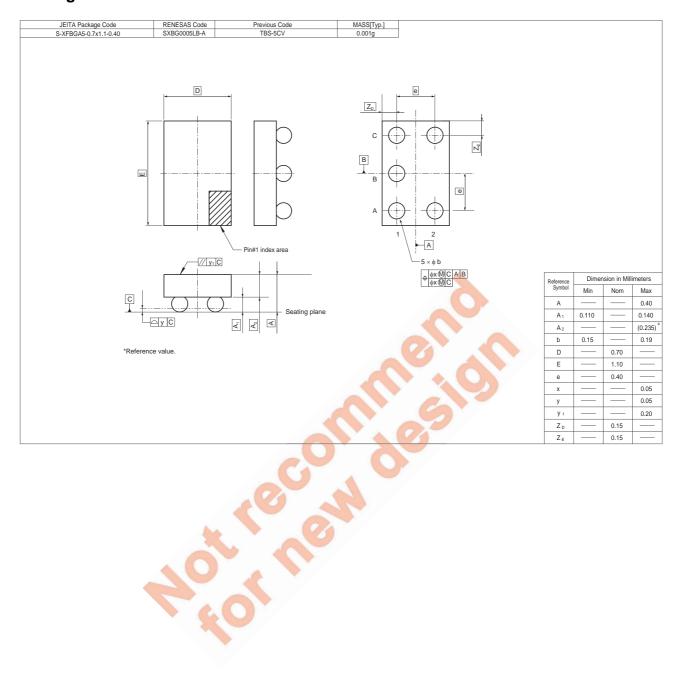
.,	INPUTS			(0			
V _{CC} (V)	VI	t _r / t _f	V _{ref}	VTT	CL	R _L	ΔV	
1.8±0.15	V_{CC}	≤ 2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	1.0 kΩ	0.15 V	
2.5±0.2	V_{CC}	≤ 2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V	
3.3±0.3	V_{CC}	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	
5.0±0.5	V _{CC}	≤ 2.5 ns	V _{CC} /2	2 × V _{CC}	50 pF	500 Ω	0.3 V	



Notes: 1. C_L includes probe and jig capacitance.

- 2. Waveform—A is for an output with internal conditions such that the output is low except when disabled by the output control.
- 3. Waveform—B is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. All input pulses are supplied by generators having the following characteristics: PRR \leq 10MHz, Zo = 50 Ω .
- 5. The output are measured one at a time with one transition per measurement.

Package Dimensions



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